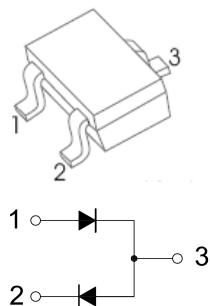


Schottky Diodes**1SS372****FEATURES**

- Small Package
- Low Forward Voltage

APPLICATIONS

- High Speed Switching

SOT-323**MAXIMUM RATINGS ($T_a=25^\circ\text{C}$ unless otherwise noted)**

Symbol	Parameter	Value	Unit
V_R	DC Blocking Voltage	10	V
I_o	Forward Continuous Current	100	mA
I_{FM}	Peak Forward Current	200	mA
I_{FSM}	Surge Current@10ms	1	A
P_D	Power Dissipation	100	mW
$R_{\theta JA}$	Thermal Resistance From Junction To Ambient	1000	°C/W
T_j	Junction Temperature	125	°C
T_{stg}	Storage Temperature	-55~+150	°C

ELECTRICAL CHARACTERISTICS($T_a=25^\circ\text{C}$ unless otherwise specified)

Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
Reverse voltage	$V_{(BR)}$	$I_R=100\mu\text{A}$	10			V
Reverse current	I_R	$V_R=10\text{V}$			20	μA
Forward voltage	V_F	$I_F=1\text{mA}$		0.18		V
		$I_F=5\text{mA}$		0.3		
		$I_F=100\text{mA}$			0.5	
Total capacitance	C_{tot}	$V_R=0\text{V}, f=1\text{MHz}$			40	pF